

R2A20168NP/SA/SP

8-bit 8ch D/A Converter with Buffer Amplifiers

R03DS0019EJ0200

Rev.2.00

Jul 03, 2013

Description

The R2A20168 is an integrated circuit semiconductor of CMOS structure with 8 channels of built in D/A unnecessary and enabling configuration of a system with few component parts.

Serial data transfer type input can easily be used through a combination of three lines: DI, CLK, and LD.

Outputs incorporate buffer op-amps that have a drive capacity of 1 mA or above for both sink source, and can operate over the entire voltage range from almost ground to Vcc (0 to 5V), making peripheral elements unnecessary and enabling configuration of a system with few component parts.

Very small QFN package is added to lineup. It is suitable for a small mounting and reduces the mounting area.

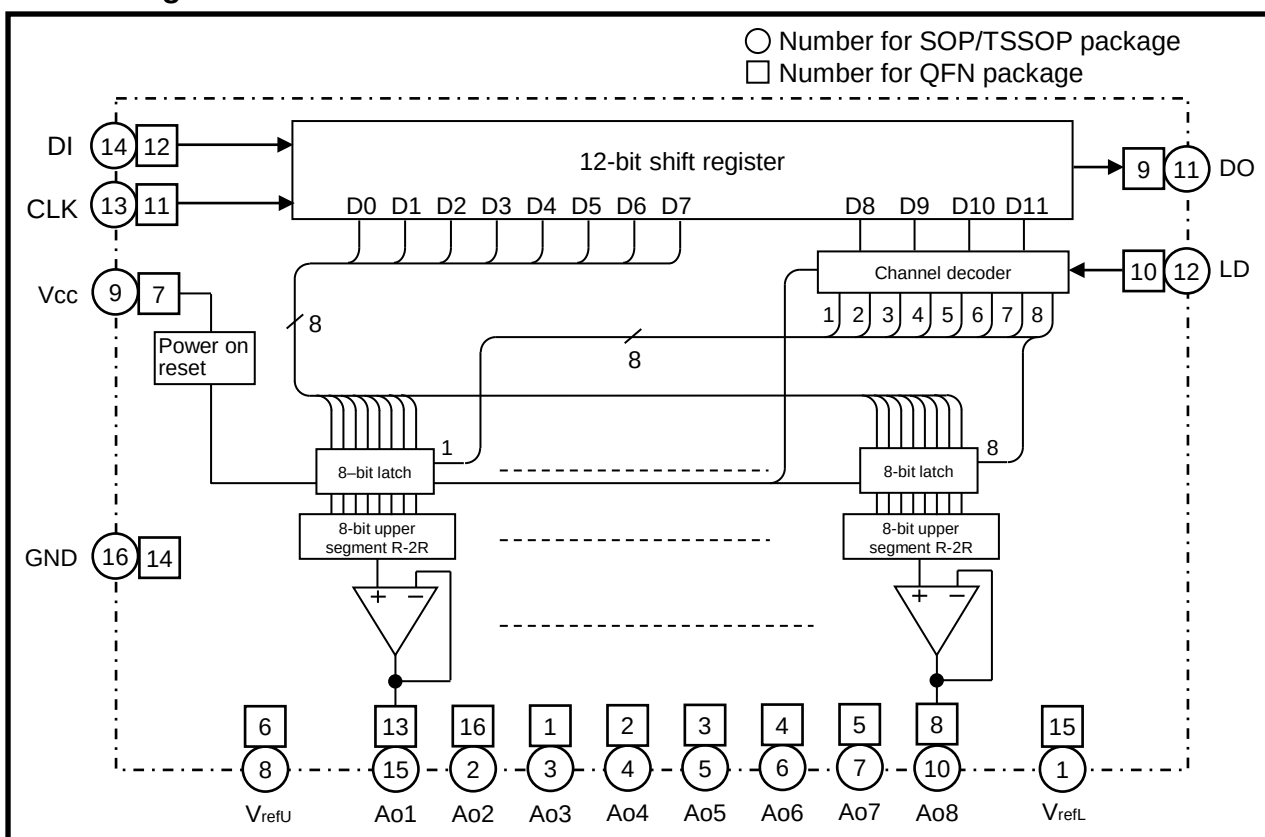
Features

- Guarantee Nonlinearity error : $\pm 1.0\text{LSB}$, Differential nonlinearity error : $\pm 0.7\text{LSB}$
- Data transfer format: 12-bit serial data input type by 3 wire (DI, SCK, LD)
- Output buffer op-amps: Operable over entire voltage range from almost ground to Vcc (0 to 5V)
- Very small size package line-up: QFN-16(pin pitch: 0.5mm), TSSOP-16(pin pitch 0.65mm)

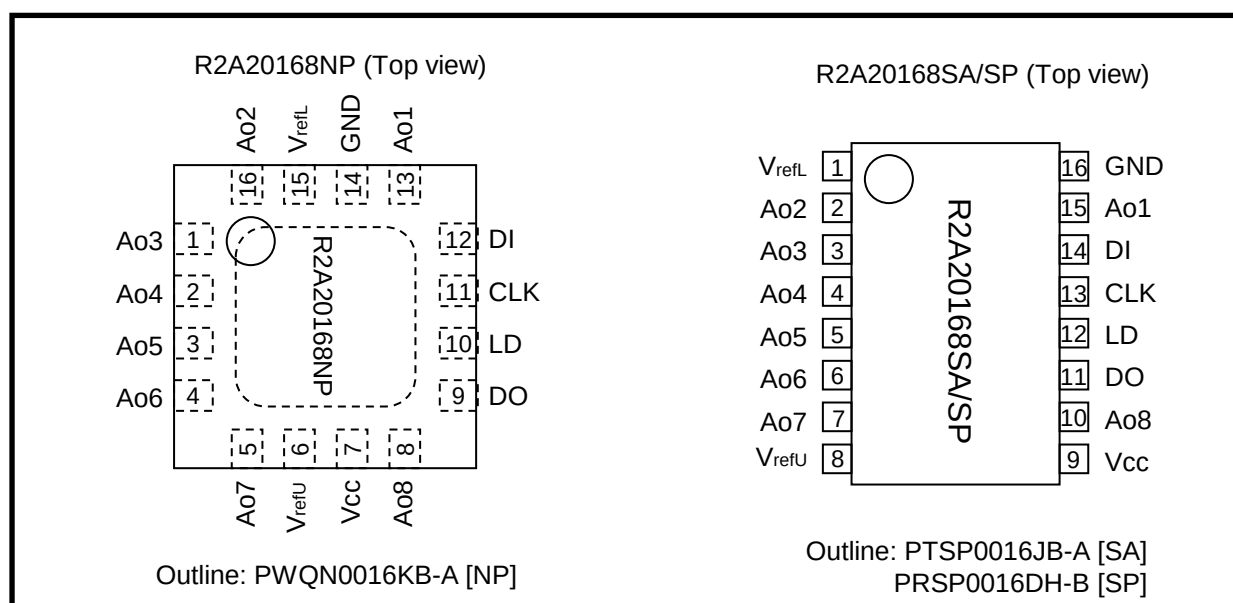
Application

- Conversion from digital data to analog control data for home-use and industrial equipment.
- Signal gain control or automatic adjustment of LCD-TV, PDP-TV or LCD display-monitor.
- Blurring correction control or various control of the interchangeable lens of digital still camera.
- Automatic adjustment by combination with microcomputer and EEPROM.
(substitution of half fixed resistance)

Block Diagram



Pin Arrangement



Pin Description

Pin No.		Symbol	Function
[QFN]	[TSSOP /SOP]		
12	14	DI	Serial data input terminal. (Input serial data with a 12-bit data length)
11	13	CLK	Serial clock input terminal (Input signal from DI terminal is input to 12-bit shift register at rise of serial clock.)
10	12	LD	Load terminal (When High level is input to LD terminal, value in 12-bit shift register is loaded into decoder and 8-bit latch.)
9	11	DO	Serial data output terminal (Data is sequentially output from the MSB bit.)
13	15	Ao1	8-bit resolution D/A converter output terminals (After power on, all channels are reset and DAC data 00h is output.)
16	2	Ao2	
1	3	Ao3	
2	4	Ao4	
3	5	Ao5	
4	6	Ao6	
5	7	Ao7	
8	10	Ao8	
7	9	Vcc	Power supply terminal
14	16	GND	GND terminal
6	8	VrefU	D/A converter upper reference voltage input terminal
15	1	VrefL	D/A converter lower reference voltage input terminal

Absolute Maximum Ratings

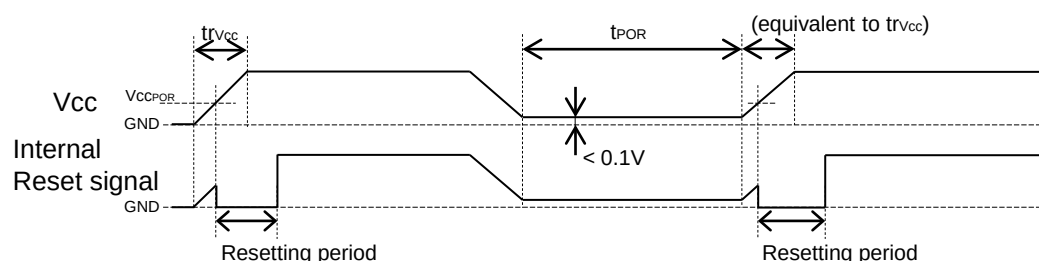
(Ta = +25deg unless otherwise noted)

Item	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		-0.3 to +6.5	V
D/A converter upper reference voltage	V _{refU}		-0.3 to +6.5	V
D/A converter lower reference voltage	V _{refL}		-0.3 to +6.5	V
Buffer amplifier output current	I _{AO}	Continuous	-2.0 to +2.0	mA
Input voltage	V _{in}		-0.3 to V _{CC} +0.3 <+6.5	V
Output voltage	V _o		-0.3 to V _{CC} +0.3 <+6.5	V
Power dissipation	P _d	Ta = +85deg	290(NP) / 150(SA) / 300(SP)	mW
Thermal derating factor	K theta	Ta > +25deg	7.25(NP) / 3.75(SA) / 7.5(SP)	mW/deg
Operating temperature	T _{opr}		-30 to +85	deg
Storage temperature	T _{stg}		-40 to +125	deg

Electrical Characteristics« Digital Part » (V_{CC}, V_{refU} = +5V +/-10%, V_{CC} > V_{refU}, GND, V_{refL} = 0V, Ta = -30 to +85deg, Unless otherwise noted)

Item	Symbol	Test conditions	Limits			Unit
			Min	Typ	Max	
Supply voltage	V _{CC}		2.7	5.0	5.5	V
Supply current	I _{CC}	CLK = 1MHz, V _{CC} = 5V, I _{AO} = 0μA	-	0.4	1.2	mA
Input leak current	I _{ILK}	V _{IN} = 0 to V _{CC}	-10	-	10	μA
Input low voltage	V _{IL}		-	-	0.2V _{CC}	V
Input high voltage	V _{IH}	4.0V < V _{CC}	0.55V _{CC}	-	-	V
		V _{CC} ≤ 4.0V	0.8V _{CC}	-	-	V
Output low voltage	V _{OL}	4.0V < V _{CC} , I _{OL} = 2.0mA	-	-	0.4	V
		V _{CC} < 4.0V, I _{OL} = 1.5mA	-	-	0.4	V
Output high voltage	V _{OH}	I _{OH} = -400μA	V _{CC} - 0.4	-	-	V
Supply voltage rise time *1	t _{rVCC}	V _{CC} = 0 to 2.7V	100	-	-	μs
Internal reset operating voltage *1	V _{CCPOR}	V _{CC} = 0 to 2.7V	-	1.5	1.9	V
Power supply restart interval (Power supply OFF ON) *1	t _{POR}	V _{CC} < 0.1V	1	-	-	ms

*1 : When power supply is turned on, internal circuit is initialized by power on reset circuit. But, if re-powered on quickly, initialize is not operate. So, keep the time period of re-powered on (t_{POR}).



« Analog Part » (V_{CC} , $V_{refU} = +5V \pm 10\%$, $V_{CC} > V_{refU}$, GND , $V_{refL} = 0V$, $T_a = -30$ to $+85^\circ\text{C}$, Unless otherwise noted)

Item	Symbol	Test conditions	Limits			Unit
			Min	Typ	Max	
Current dissipation	I_{refU}	$V_{refU}=5V$, $V_{refL}=0V$, $I_{AO}=0\mu A$, Data condition: at maximum current	-	1.0	2.0	mA
D/A converter upper reference voltage range *2	V_{refU}	$V_{CC} \geq 4.5V$	3.5	-	V_{CC}	V
		$V_{CC} < 4.5V$	$0.7V_{CC}$	-	V_{CC}	
D/A converter lower reference voltage range *2	V_{refL}	$V_{CC} \geq 4.5V$	GND	-	$V_{CC}-3.5$	V
		$V_{CC} < 4.5V$	GND	-	$0.3V_{CC}$	
Buffer amplifier output voltage range	V_{AO}	$I_{AO} = \pm 100 \mu A$	0.1	-	$V_{CC} - 0.1$	V
		$I_{AO} = \pm 500 \mu A$	0.2	-	$V_{CC} - 0.2$	V
Buffer amplifier output drive range	I_{AO}	Upper side saturation voltage = 0.3V, Lower side saturation voltage = 0.2V	-1.0	-	1.0	mA
Differential nonlinearity	S_{DL}	$V_{refU} = 4.79V$, $V_{refL} = 0.95V$, $V_{CC} = 5.5V$ (15mV/LSB), Without load ($I_{AO} = 0\mu A$)	-0.7	-	0.7	LSB
Nonlinearity	S_L		-1.0	-	1.0	LSB
Zero code error	S_{ZERO}		-2.0	-	2.0	LSB
Full scale error	S_{FULL}		-2.0	-	2.0	LSB
Output capacitive load	C_O		-	-	0.1	μF
Buffer amplifier output impedance	R_O		-	5.0	-	ohm

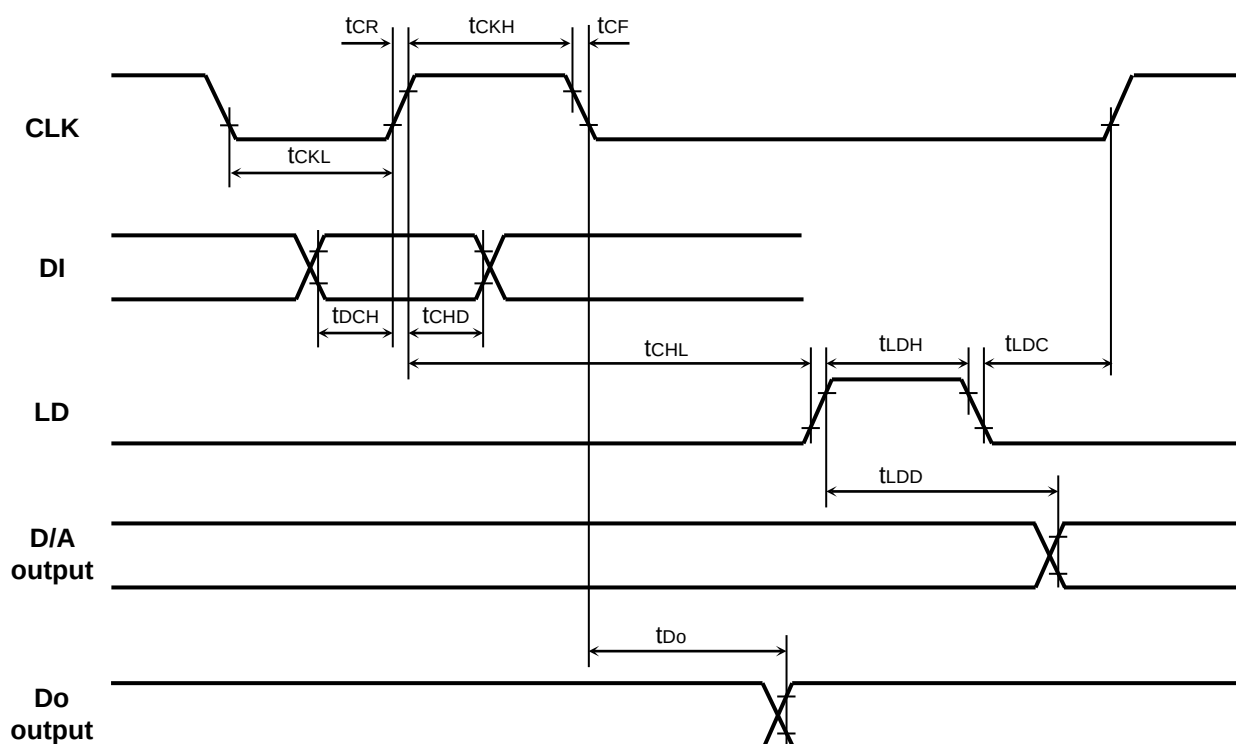
*2 : The output does not necessary be the value with the reference voltage setting range.
The output value is determined by the buffer amplifier output voltage range (V_{AO}).

AC Characteristics

($V_{CC}, V_{refU} = +5V \pm 10\%$, $V_{CC} \geq V_{refU}$, $GND = V_{refL} = 0V$, $T_a = -30$ to $+85^\circ\text{C}$, unless otherwise noted)

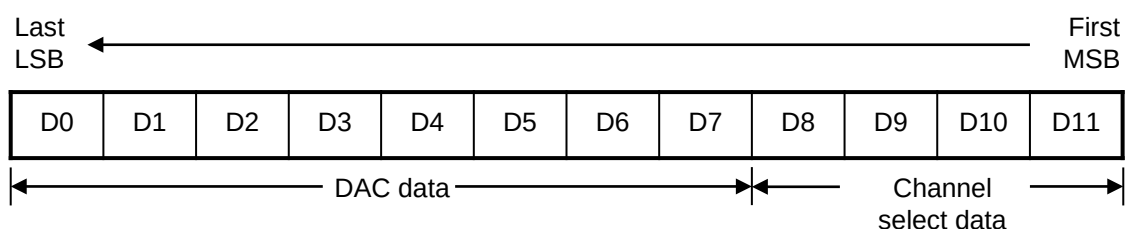
Item	Symbol	Test conditions	Limits			Unit
			Min	Typ	Max	
Clock frequency	f_{CLK}		-	1.0	10	MHz
Clock low pulse width	t_{CKL}		40	-	-	ns
Clock high pulse width	t_{CKH}		40	-	-	ns
Clock rise time	t_{CR}		-	-	200	ns
Clock fall time	t_{CF}		-	-	200	ns
Data setup time	t_{DCH}		4	-	-	ns
Data hold time	t_{CHD}		30	-	-	ns
LD setup time	t_{CHL}		40	-	-	ns
LD hold time	t_{LDC}		40	-	-	ns
LD high pulse width	t_{LDH}		40	-	-	ns
Data output delay time	t_{DO}	$C_L < 100 \text{ pF}$	-10	-	50	ns
D/A output settling time	t_{LDD}	$T_a = 25^\circ\text{C}$, $C_L < 100 \text{ pF}$, $V_{AO}: 0.5 \rightarrow 4.5 \text{ V}$, The time until the output becomes the final value of 1/2 LSB.	-	-	150	μs

Timing Chart



(Note) Timing chart above is a schematic representation of the timing of each signal type.
CLK signal input is High or Low regardless, LD signal High input is enabled.

Digital Data Format



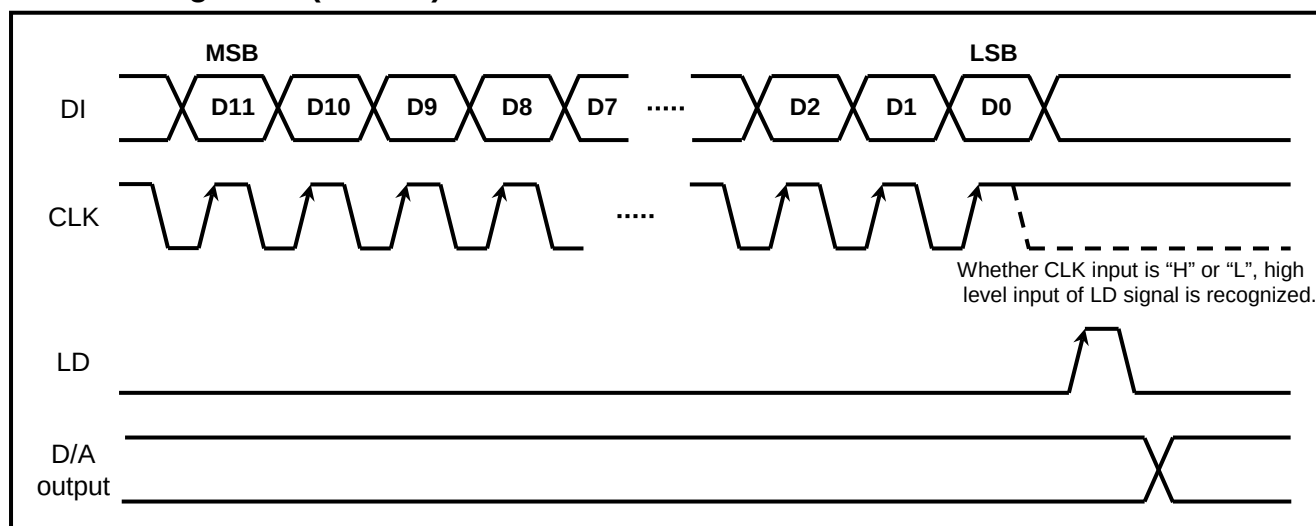
Channel select data

D8	D9	D10	D11	Chanel Selection
0	0	0	0	Don't care
0	0	0	1	Ao1 select
0	0	1	0	Ao2 select
0	0	1	1	Ao3 select
0	1	0	0	Ao4 select
0	1	0	1	Ao5 select
0	1	1	0	Ao6 select
0	1	1	1	Ao7 select
1	0	0	0	Ao8 select
1	0	0	1	Don't care
:	:	:	:	:
1	1	1	0	Don't care
1	1	1	1	Don't care

DAC data

D0	D1	D2	D3	D4	D5	D6	D7	D/A Output
0	0	0	0	0	0	0	0	$(V_{refU} - V_{refL}) / 256 \times 1 + V_{refL}$
1	0	0	0	0	0	0	0	$(V_{refU} - V_{refL}) / 256 \times 2 + V_{refL}$
0	1	0	0	0	0	0	0	$(V_{refU} - V_{refL}) / 256 \times 3 + V_{refL}$
1	1	0	0	0	0	0	0	$(V_{refU} - V_{refL}) / 256 \times 4 + V_{refL}$
:	:	:	:	:	:	:	:	:
0	1	1	1	1	1	1	1	$(V_{refU} - V_{refL}) / 256 \times 255 + V_{refL}$
1	1	1	1	1	1	1	1	V_{refU}

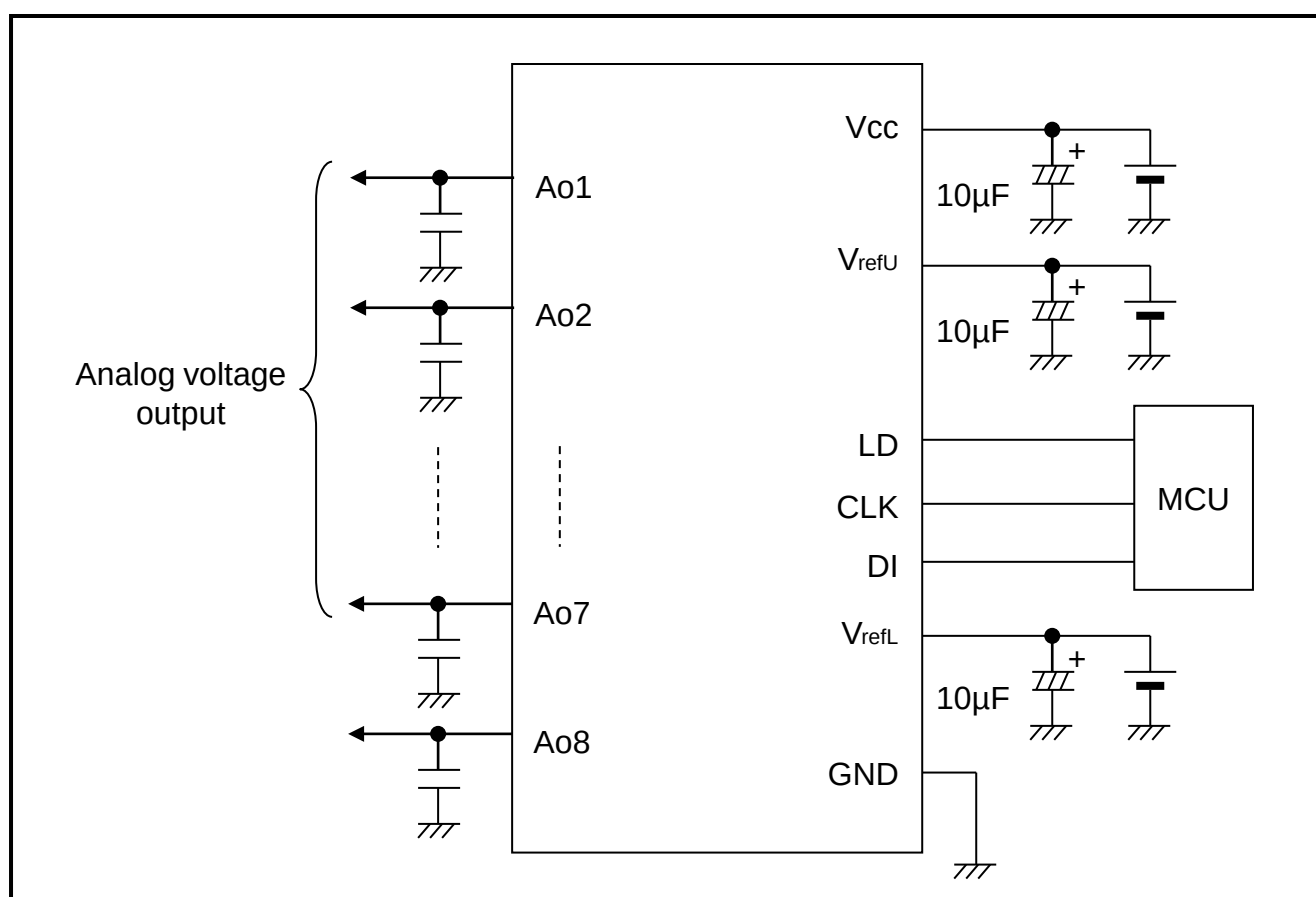
Data Timing Chart (Model)



Precaution For Use

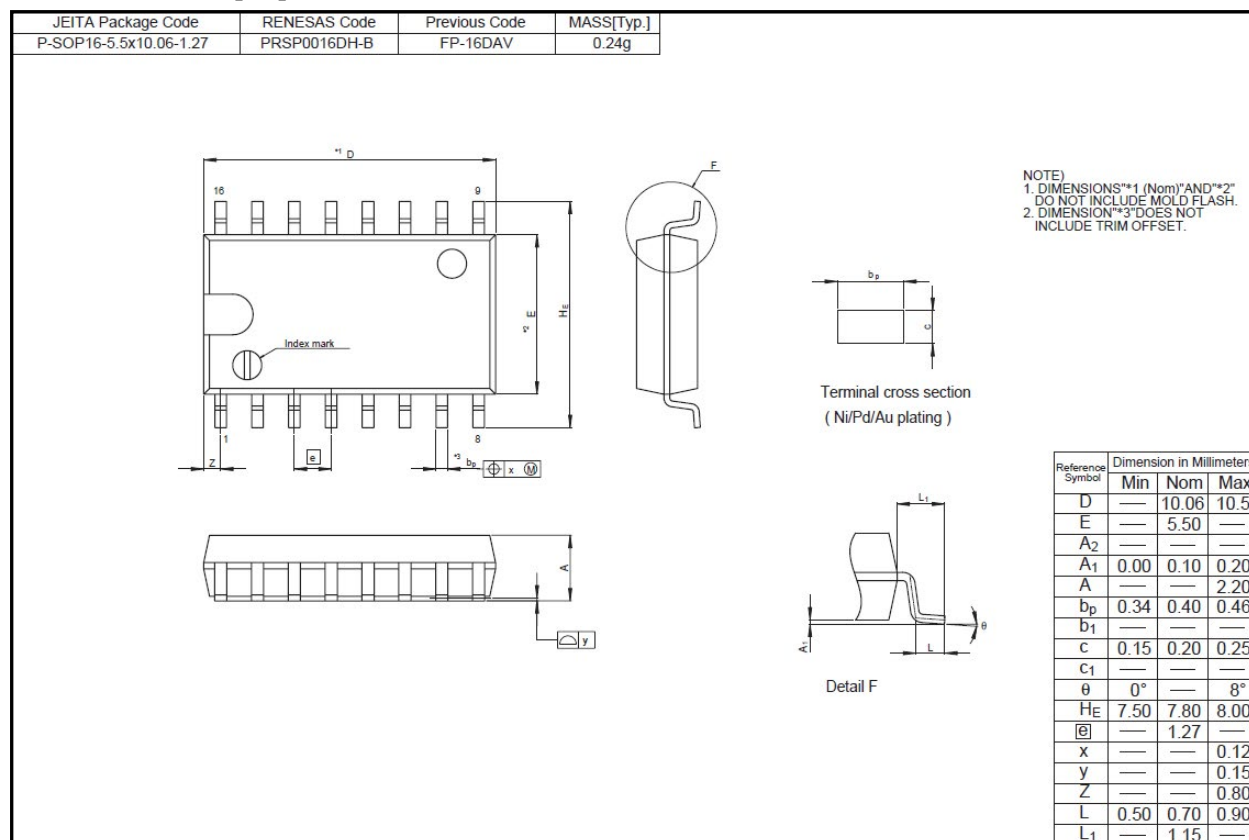
- There are three terminals (V_{CC} , V_{refU} , V_{refL}) that should be impressed a constant voltage. When ripple or spike noise is input to this terminal, there is fear that the accuracy of D/A conversion becomes lower and this IC malfunction. So, when use this IC, please connect capacitor between these terminals (V_{CC} , V_{refU} , V_{refL}) and GND for stable D/A conversion.
- This IC's output amplifier has an advantage to capacitive load, So, it's no problem at device action when connect capacitor ($0.1\mu\text{F}$ Max) among output to GND for every noise elimination.

Standard Application Circuit

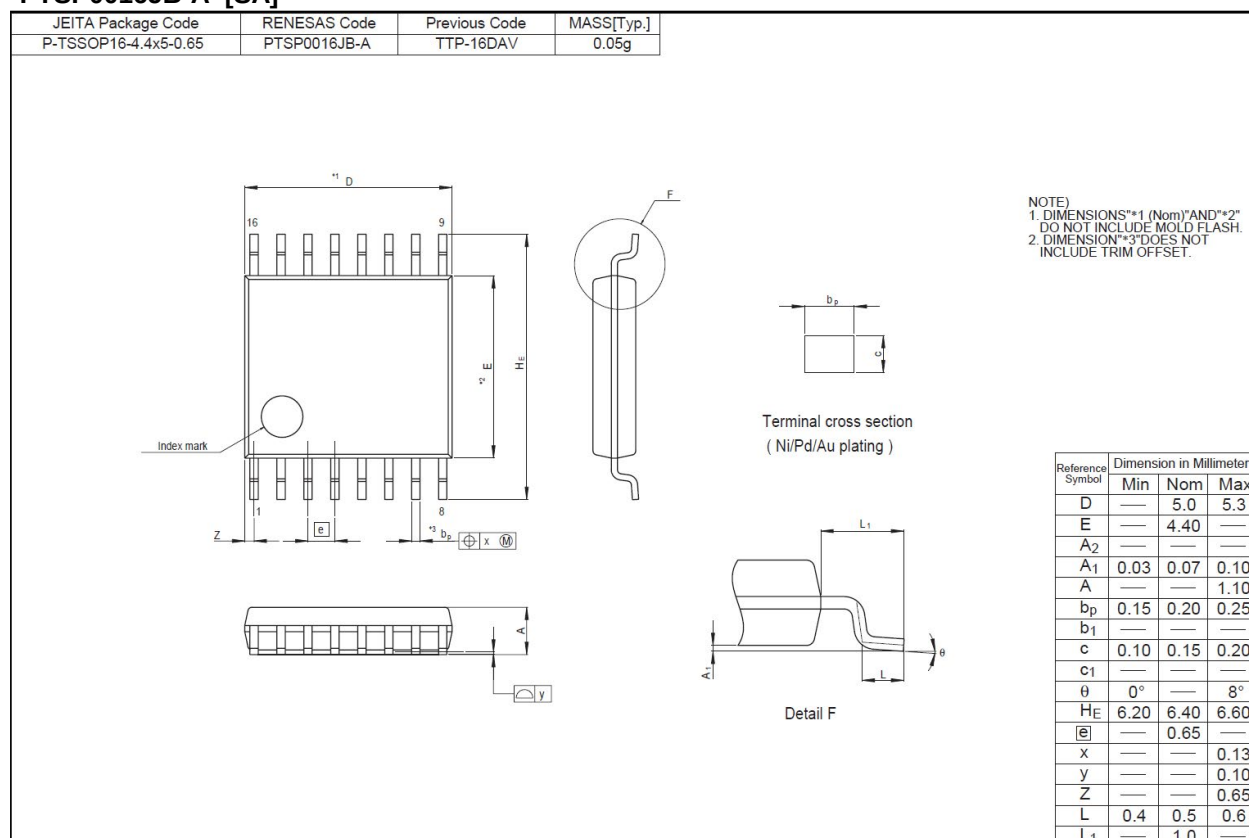


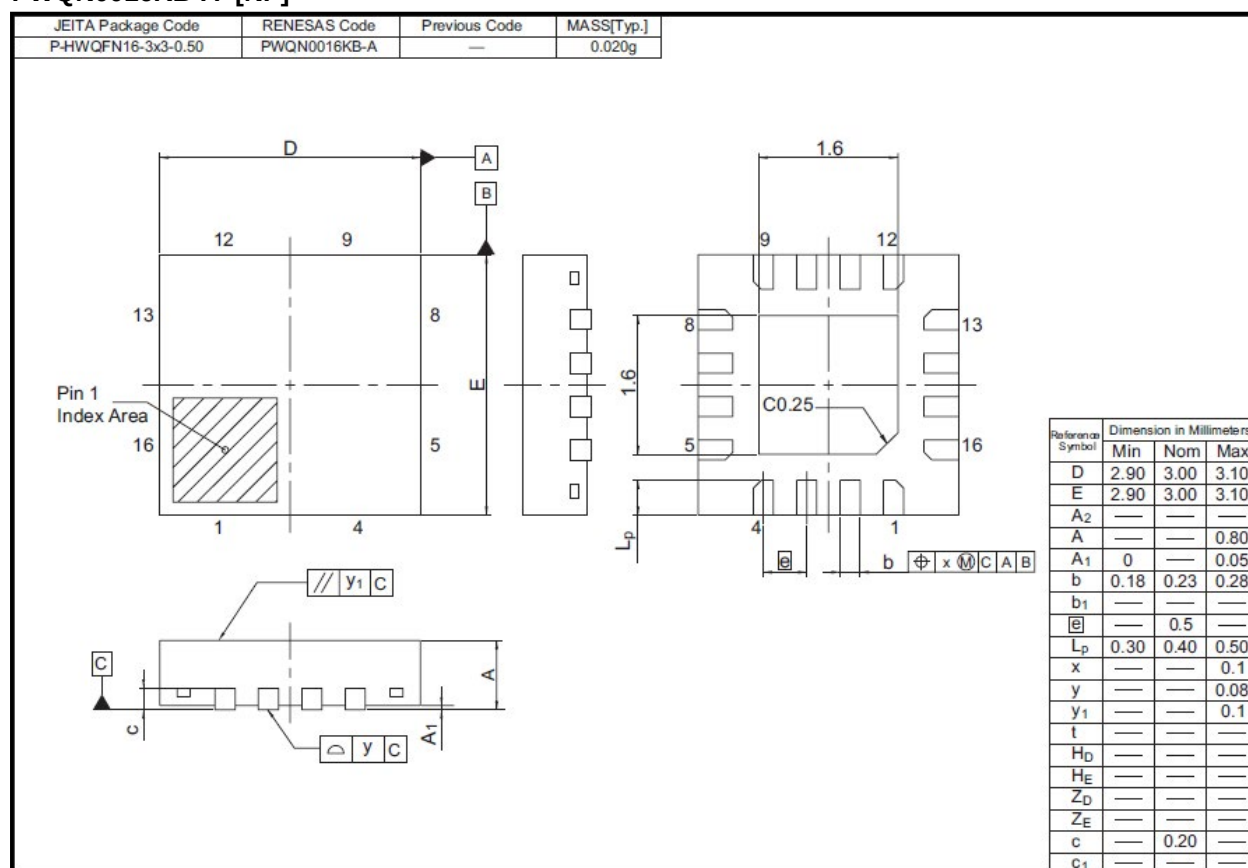
Package Dimensions

PRSP0016DH-B [SP]



PTSP0016JB-A [SA]



PWQN0016KB-A [NP]**Ordering Information**

Order part No.	Package Name	Package Code	Package type No.	Packing/Quantity
R2A20168SP	SOP-16	PRSP0016DH-B	SP	Embossed Taping/2,000 pcs.
R2A20168SA	TSSOP-16	RTSP0016JB-A	SA	Embossed Taping/2,000 pcs.
R2A20168NP	QFN-16	PWQN0016KB-A	NP	Embossed Taping/3,000 pcs.

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